



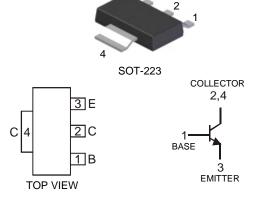
NPN SURFACE MOUNT TRANSISTOR

DZT5551

Features

- **Epitaxial Planar Die Construction**
- Complementary PNP Type Available (DZT5401)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 3)
- **Mechanical Data**
- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper Leadframe . (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram Marking & Type Code Information: See Page 3

- Ordering Information: See Page 3 Weight: 0.112 grams (approximate)



Schematic and Pin Configuration

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Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current	Ι _C	600	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation $@T_A = 25^{\circ}C$ (Note 3)	PD	1	W
Thermal Resistance, Junction to Ambient $@T_A = 25^{\circ}C$ (Note 3)	$R_{ heta JA}$	125	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	180	_	V	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	160	_	V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0	_	V	$I_{E} = 10 \mu A, I_{C} = 0$
Collector Cutoff Current	I _{CBO}	_	50	nA μA	$V_{CB} = 120V, I_E = 0$ $V_{CB} = 120V, I_E = 0, T_A = 100^{\circ}C$
Emitter Cutoff Current	I _{EBO}	_	50	nA	$V_{EB} = 4.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)					
DC Current Gain	hFE	80 80 30	250 —	—	$ I_C = 1.0mA, V_{CE} = 5.0V \\ I_C = 10mA, V_{CE} = 5.0V \\ I_C = 50mA, V_{CE} = 5.0V $
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.15 0.20	V	$I_{C} = 10$ mA, $I_{B} = 1.0$ mA $I_{C} = 50$ mA, $I_{B} = 5.0$ mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	1.0	V	$I_{C} = 10$ mA, $I_{B} = 1.0$ mA $I_{C} = 50$ mA, $I_{B} = 5.0$ mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	_	6.0	pF	$V_{CB} = 10V, f = 1.0MHz, I_E = 0$
Small Signal Current Gain	h _{fe}	50	200		$V_{CE} = 10V, I_{C} = 1.0mA, f = 1.0kHz$
Current Gain-Bandwidth Product	f _T	100	300	MHz	$V_{CE} = 10V, I_{C} = 10mA, f = 100MHz$
Noise Figure	NF	_	8.0	dB	$V_{CE} = 5.0V$, $I_C = 200\mu A$, $R_S = 1.0k\Omega$, $f = 1.0kHz$

1. No purposefully added lead.

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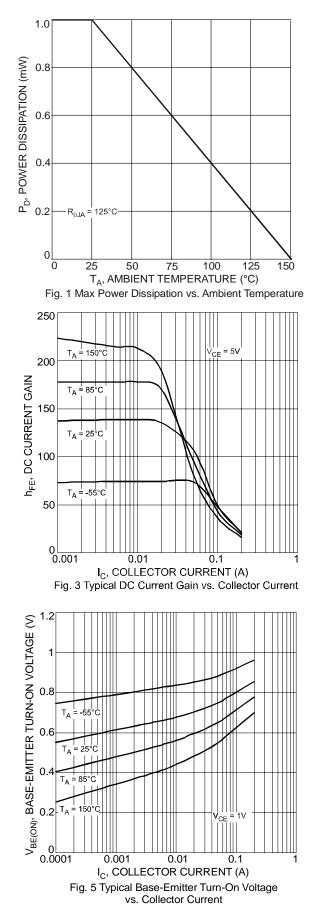
Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php. Device mounted on FR-4 PCB, pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our 3. website at http://www.diodes.com/datasheets/ap02001.pdf.

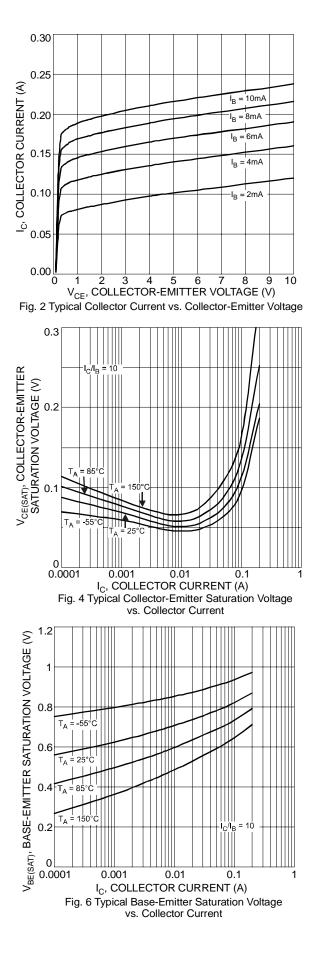
4. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.

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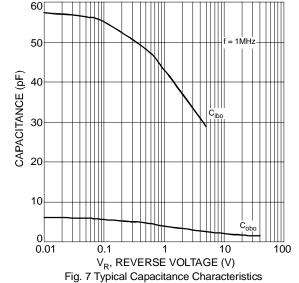
Notes:

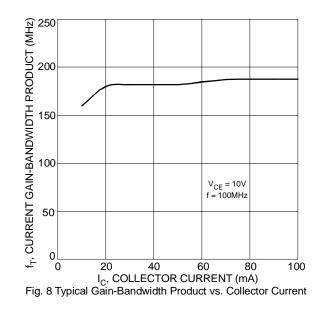










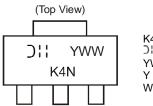


Ordering Information (Note 5)

Device	Packaging	Shipping
DZT5551-13	SOT-223	2500/Tape & Reel

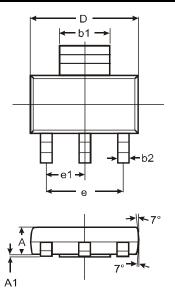
Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

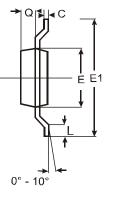
Marking Information



K4N = Product type marking code DII = Manufacturer's code marking YWW = Date code marking Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52

Package Outline Dimensions

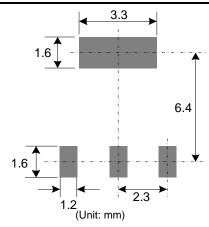




SOT-223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	—	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					



Suggested Pad Layout



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